Autonics



Фотоелектричні датчики Каталог 2023

A1. Photoelectric Sensors

Photoelectric sensors are used to detect distance, absence or presence of objects using a light transmitter and receiver.

41-1 i	Rectangular	BTS Series	W 7.2 mm Photoelectric Sensors
		BJ Series	Rectangular Photoelectric Sensors (Cable Type)
			Rectangular Photoelectric Sensors (Connector Type)
		BJX Series	Rectangular Photoelectric Sensors
		BM Series	General Photoelectric Sensors
		BMS Series	Side Sensing Photoelectric Sensors
		BY Series	Photoelectric Sensors with Synchronous Detection
		BYD Series	Photoelectric Sensors with Built-In Timer
		BH Series	Front / Side Mount Photoelectric Sensors
		BA Series	Diffuse Reflective Long-Distance Photoelectric Sensors
A1-2	Compact	BTF Series	L 3.7 mm Flat Photoelectric Sensors
		BPS Series	L 7.5 mm Flat Photoelectric Sensors
A1-3	Cylindrical	BRQ Series	Cylindrical Photoelectric Sensors (Front Sensing Type)
			Cylindrical Photoelectric Sensors (Side Sensing Type)
		BR Series	Cylindrical Photoelectric Sensors
A1-4	U-Shaped	BUM Series	4-Channel U-Shaped Photoelectric Sensors
		BUP Series	1-Channel U-Shaped Photoelectric Sensors
A1-5	AC/DC	BEN Series	Universal AC / DC Photoelectric Sensors
		BX Series	Universal AC / DC Photoelectric Sensors
A1-6	PCB Detection	BJP Series	Photoelectric Sensors for PCB Detection
A1-7	Oil-Resistant / Oil-Proof	BJR Series	Oil-Resistant Photoelectric Sensors
	THE PERSON NAMED IN	BJR-F Series	Oil-Proof Photoelectric Sensors
A1-8	Color Mark	BC Series	Color Mark Photoelectric Sensors
A1-9	Liquid Level	BL Series	Liquid Level Photoelectric Sensors

W 7.2 mm

Photoelectric Sensors

BTS Series



Features

- W 7.2 mm Photoelectric Sensors
- W 7.2 \times H 18.6 \times L 9.5 mm (Through-beam type)
- W 7.2 × H 24.6 × L 10.8 mm (Retroreflective, convergent reflective type)
- Detection methods and minimum target size
- Through-beam type (BTS1M): Ø 2 mm
- Retroreflective type (BTS200): Ø 2 mm (sensing distance: 100 mm)
- Convergent reflective type (BTS15/BTS30): Ø 0.15 mm (sensing distance: 10 mm)
- · Maximum sensing distance: 1 m (Through-beam type)
- · Operation indicator (red) and stability indicator (green) show operation status
- Stainless steel (SUS304) mounting brackets
- IP67 protection rating (IEC standard)

Specifications

Model	BTS1M-TDT□-□	BTS200-MDT□-□	BTS□-LDT□-□			
Sensing type	Through-beam	Retroreflective	Convergent reflective			
Sensing distance	1 m	10 to 200 mm ⁰¹⁾	5 to 15 mm $^{02)}$ 5 to 30 mm $^{02)}$			
Sensing target	Opaque materials	≥ Ø 27 mm Opaque materials	Opaque materials, translucent materials			
Min. sensing target	≥ Ø 2 mm	≥ Ø 2 mm ⁰³⁾	≥ Ø 0.15 mm ⁰⁴⁾			
Hysteresis	-	-	≤ 15 % of sensing distance			
Response time	≤1 ms					
Light source	Red LED					
Peak emission wavelength	650 nm					
Operation mode	Light ON mode / Dark ON mode model					
Indicator	Operation indicator (red), stability indicator (green)					
Approval	C € ERE	C € EH[C€ EHI			
Unit weight (packaged)	≈ 40 g (≈ 65 g)	≈ 25 g (≈ 45 g)	≈ 25 g (≈ 45 g)			

- 01) Reflector (MS-6)
 02) Non-glossy white paper 50 × 50 mm
 03) Sensing distance 100 mm
 04) Sensing distance 10 mm

04) Sensing distance to min	
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)
Current consumption	It depends on the sensing type
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 20 mA
Reflective	≤ 20 mA
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 26.4 VDC==
Load current	≤ 50 mA
Residual voltage	NPN:≤1 VDC, PNP:≤2 VDC
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	± 240 VDC== the square wave noise (pulse width: 1 μ s) by the noise simulator
Dielectric strength	1,000 VAC $\sim 50/60$ Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 10,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-20 to 55 °C, storage: -30 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP67 (IEC standard)
Connection	Cable type
Cable spec.	Ø 2.5 mm, 3-wire (emitter: 2-wire), 2 m
Wire spec.	AWG 28 (0.08 mm, 19-core), insulator outer diameter: Ø 0.9 mm
Material	Case: PBT, sensing part: PMMA, bracket: SUS304, bolt: SWCH10A



Rectangular

Photoelectric Sensors

(Cable Type)

BJ Series



Features

- Compact size: W 10.6 × H 32 × L 20 mm
- \cdot IP65 protection rating (IEC standard)
- · Adjuster for selecting Light ON / Dark ON mode
- · Built-in sensitivity adjustment adjuster (except BJG30-DDT)
- · Reverse power protection circuit, output short overcurrent protection circuit
- Mutual interference prevention function (except through-beam and BGS reflective type)
- · Excellent noise immunity and minimal influence from ambient light

Specifications

Model	BJ□-	BJ□-TDT-□		BJ3M-PDT-□	BJ□-BDT	BJ□-BDT-□		BJN□-NDT-□	
Sensing type	Throu	Through-beam		Polarized retroreflective	BGS reflective		Narrow beam reflective		
Sensing distance	7 m	10 m	15 m	3 m ⁰¹⁾	10 to 30 mm ⁰²⁾	10 to 50 mm ⁰²⁾	30 to 70 mm ⁰³⁾	70 to 130 mm ⁰³⁾	
Sensing target	Opaqu	ue mate	rials	Opaque materials	Opaque materials, translucent materials		Opaque materials, translucent materials		
Min. sensing target	≥ ≥ Ø8 Ø12 mm mm		≥ Ø 75 mm	-		≥ Ø 0.2 mm (copper wire)			
Hysteresis	-		-	≤ 10% of sensing distance		≤ 25% of sensing distance	≤ 20% of sensing distance		
Black/white difference	-			-	≤ 10% of sensing distance		-		
Response time	≤ 1 ms	≤ 1 ms		≤ 1 ms	≤ 1.5 ms	≤ 1.5 ms			
Light source	Red Red Infrared		Red	Red		Red			
Peak emission wavelength	650 660 850 nm nm nm		660 nm	660 nm		650 nm			
Min. spot size	-			-	≈ Ø 5.0 mm	≈ Ø 4.5 mm	≈ Ø 2.0 mm	≈ Ø 2.5 mm	
Sensitivity adjustment	YES (A	Adjuster)	YES (Adjuster)	YES (Adjuster) 04)		YES (Adjuster)		
Mutual interference prevention	-		YES	-		YES			
Operation mode	Light ON mode - Dark O			N mode selectable (Adjuster)					
Indicator	Operation indicator (red)), stability indicator (r (green), power indicator (green) 05)				
Approval	C € EH	[C € ERI	C € EHI		C € ERI		
Unit weight (packaged)	≈ 90 g	(≈ 115	g)	≈ 60 g (≈ 85 g)	≈ 50 g		≈ 45 g		

- Oil) Reflector (MS-2A)

 02) Non-glossy white paper 50 × 50 mm

 03) Non-glossy white paper 100 × 100 mm

 04) -10% of max. sensing distance, Non-glossy white paper

 05) Only for the emitter



Model	BJ□-DDT-□			BJG30 -DDT
Sensing type	Diffuse reflective			Diffuse reflective
Sensing distance	100 mm ⁰¹⁾	300 mm ⁰¹⁾	1 m ⁰²⁾	15 mm ⁰³⁾ or 30 mm ⁰¹⁾
Sensing target	Opaque materials, translucent materials			Transparent glass or opaque materials, translucent materials
Hysteresis	≤ 20% of sens	sing distance		≤ 20% of sensing distance
Response time	≤ 1 ms			≤ 1 ms
Light source	Infrared	Red	Infrared	Infrared
Peak emission wavelength	850 nm	660 nm	850 nm	850 nm
Sensitivity adjustment	YES (Adjuster)		-
Mutual interference prevention	YES			YES
Operation mode	Light ON mod (Adjuster)	e - Dark ON mo	de selectable	Light ON
Indicator	Operation indicator (red), stability indicator (green)			Operation indicator (red), stability indicator (green)
Approval	C € EHI			C € EHI
Unit weight (packaged)	≈ 45 g (≈ 70 g)		≈ 45 g

⁰¹⁾ Non-glossy white paper 100 \times 100 mm 02) Non-glossy white paper 300 \times 300 mm 03) Transparent Glass 50 \times 50 mm, t = 3.0 mm

,	as) Harisparent Glass 50 × 50 mm, t = 5.0 mm						
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)						
Current consumption	It depends on the sensing type						
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 20 mA						
Reflective	≤ 30 mA						
Control output	NPN open collector output / PNP open collector output model						
Load voltage	≤ 26.4 VDC==						
Load current	≤ 100 mA						
Residual voltage	NPN : \leq 1 VDC==, PNP : \leq 2.5 VDC== (BGS reflective type : \leq 2 VDC==)						
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit						
Insulation resistance	≥ 20 MΩ (500 VDC== megger)						
Noise immunity	$\pm 240\text{VDC} =$ the square wave noise (pulse width: 1 $\mu s)$ by the noise simulator						
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min						
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours						
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times						
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx						
Ambient temperature	-25 to 55 °C, storage: -40 to 70 °C (no freezing or condensation)						
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)						
Protection rating	IP65 (IEC standard)						
Connection	Cable type						
Cable spec.	Ø 3.5 mm, 3-wire (emitter: 2-wire), 2 m						
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1 mm						
Material	Case: PC+ABS, CAP: PC, sensing part: PMMA, bracket: SUS304, bolt: SCM, nut: SCM, sleeve: Brass, Ni-plate						

Rectangular

Photoelectric Sensors

(Connector Type)

BJ Series



Features

- Compact size: W 10.6 × H 32 × L 20 mm
- IP67 protection rating (IEC standard)
- · Adjuster for selecting Light ON / Dark ON mode
- · Built-in sensitivity adjustment adjuster
- \cdot Reverse power protection circuit, output short overcurrent protection circuit
- $\cdot \, \text{Mutual interference prevention function} \\$
- Excellent noise immunity and minimal influence from ambient light
- · High performance lens with long sensing distance
- · Long sensing distance : Through-beam type 15 m, diffuse reflective type 1 m, polarized retroreflective type 3 m (MS-2A)
- M.S.R. (Mirror Surface Rejection) function (Polarized retroreflective type)

Specifications

Model	BJ□-TDT-C-		BJ3M-PDT-C-□	BJ□-DD	T-C-□	
Sensing type	Through-beam		Polarized retroreflective	Diffuse reflective		
Sensing distance	10 m	15 m	3 m ⁰¹⁾	100 mm	300 mm	1 m ⁰³⁾
Sensing target	Opaque materials		Opaque materials	Opaque materials, translucent materials		ls
Min. sensing target	≥ Ø 12 mm		≥ Ø 75 mm	-		
Hysteresis	-		-	≤ 20% of sensing distance		istance
Response time	≤ 1 ms		≤ 1 ms	≤ 1 ms		
Light source	Red	Infrared	Red	Infrared	Red	Infrared
Peak emission wavelength	660 nm	850 nm	660 nm	850 nm	660 nm	850 nm
Sensitivity adjustment	YES (Adjuster))	YES (Adjuster)	YES (Adjuster)		
Mutual interference prevention	-		YES	YES		
Operation mode	Light ON mod	e - Dark ON mo	de selectable (Adjuster)			
Indicator	Operation indi	cator (red), stal	oility indicator (green), power in	ndicator (g	reen) 04)	
Approval	C€ ERI		C€ EHI	C € ERI		
Unit weight (packaged)	≈ 20 g (≈ 45 g	1)	≈ 30 g (≈ 55 g)	≈ 10 g (≈ 35 g)		

- 01) Reflector (MS-2A)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)
Current consumption	It depends on the sensing type
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 20 mA
Reflective	≤ 30 mA
Control output	NPN open collector output / PNP open collector output Model
Load voltage	≤ 26.4 VDC==
Load current	≤ 100 mA
Residual voltage	NPN: ≤1 VDC==, PNP: ≤ 2.5 VDC==
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-25 to 55 °C, storage: -40 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP67 (IEC standard)
Connection	Connector type
Connector	M8 4-pin plug type
Material	Case: PC+ABS, CAP: PC, sensing part: PMMA, bracket: SUS304, bolt: SCM, nut: SCM, sleeve: Brass, Ni -plate



Rectangular

Photoelectric Sensors

BJX Series



Features

- Long sensing distance with high quality lens: Through-beam type 30 m, diffuse reflective type 1 m, polarized retroreflective type 3 m (MS-2A)
- M.S.R. (Mirror Surface Rejection) function (Polarized retroreflective type)
- Compact size : W 11 × H 32 × L 20 mm
- · Switch for selecting Light ON/Dark ON mode
- · Built-in sensitivity adjustment adjuster
- Reverse power protection circuit, output short overcurrent protection circuit
- Mutual interference prevention function (except through-beam type)
- Excellent noise immunity and minimal influence from ambient light
- IP65 protection rating (IEC standard)

Specifications

Model	BJX□-TDT-□-□			BJX3M-PDT-□-□	BJX□-D	DT-□-□		
Sensing type	Through-beam			Polarized retroreflective	Diffuse re	Diffuse reflective		
Sensing distance	10 m	15 m	30 m	3 m ⁰¹⁾	100 mm	300 mm	1 m	
Sensing target	Opaque materials			Opaque materials		Opaque materials, translucent materials		
Min. sensing target	≥ Ø 15 mm			≥ Ø 75 mm	-	-		
Hysteresis	-			-	≤ 20 % o	≤ 20 % of sensing distance		
Response time	≤ 1 ms							
Light source	Red	Infrared	Red	Red	Infrared	Red	Red	
Peak emission wavelength	660 nm	850 nm	660 nm	660 nm	850 nm	660 nm	660 nm	
Sensitivity adjustment	YES (Adj	uster)		YES (Adjuster)	YES (Adji	YES (Adjuster)		
Mutual interference prevention	-			YES	YES	YES		
Operation mode	Light ON	mode - Da	ark ON mo	de selectable (Adjuster)				
Indicator	Operation indicator (yellow), s			stability indicator (green), po	wer indicator	(red) ⁰⁴⁾		
Approval	(€ c 91) u	C€¢ \$N us EHE		C€c 9X us [H[(€ c 91 0 us	C€₀ ₹X Us ERE		
01) Deflector (MC-2A)								

- 01) Reflector (MS-2A)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

Through-beam	Polarized retroreflective	Diffuse reflective				
≈ 95 g (≈ 145 g)	≈ 50 g (≈ 115 g)	≈ 50 g (≈ 100 g)				
≈ 12 g (≈ 65 g)	≈ 6 g (≈ 75 g)	≈ 6 g (≈ 60 g)				
10-30 VDC== ±10 % (ripple P-	-P: ≤ 10 %)					
It depends on the sensing typ	oe e					
Emitter: ≤ 20 mA, receiver: ≤	20 mA					
≤ 30 mA						
NPN open collector output / F	NP open collector output mod	el				
≤ 30 VDC==						
≤ 100 mA						
NPN: ≤ 1 VDC==, PNP: ≤ 2 VD	C==					
Reverse power protection circ	cuit, output short overcurrent p	rotection circuit				
≥ 20 MΩ (500 VDC== megger)						
±240 VDC= the square wave noise (pulse width: 1 μs) by the noise simulator						
1,000 VAC~ 50/60 Hz for 1 min						
1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours						
500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times						
Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx						
-25 to 60 °C, storage: -40 to	70 °C (no freezing or condensa	ation) ⁰¹⁾				
35 to 85 %RH, storage: 35 to	85 %RH (no freezing or conde	ensation)				
IP65 (IEC standard)						
Cable type / Connector type i	model					
Ø 4 mm, 3-wire (Emitter: 2-w	ire), 2 m					
AWG26 (0.52 mm, 20-core), i	nsulator outer diameter: Ø 1 mi	m				
M8 4-pin plug type						
Case: PC, CAP: PC, sensing p	Case: PC, CAP: PC, sensing part: PMMA					
	≈ 95 g (≈ 145 g) ≈ 12 g (≈ 65 g) 10-30 VDC= ±10 % (ripple P- It depends on the sensing type mitter: ≤ 20 mA, receiver: ≤ \times 30 mA NPN open collector output / F ≤ 30 VDC= \times 100 mA NPN: ≤ 1 VDC=, PNP: ≤ 2 VD Reverse power protection circe 2 20 MΩ (500 VDC= megget ±240 VDC= the square wave 1,000 VAC \times 50/60 Hz for 1 m 1.5 mm double amplitude at fright for 2 hours 500 m/s² (≈ 50 G) in each X, Sunlight: ≤ 11,000 lx, incanded -25 to 60 °C, storage: -40 to 35 to 85 %RH, storage: 35 to 1P65 (IEC standard) Cable type / Connector type I Ø 4 mm, 3-wire (Emitter: 2-w AWG26 (0.52 mm, 20-core), i M8 4-pin plug type	≈ 95 g (≈ 145 g) ≈ 50 g (≈ 115 g) ≈ 12 g (≈ 65 g) ≈ 6 g (≈ 75 g) 10–30 VDC = ±10 % (ripple P-P: ≤ 10 %) It depends on the sensing type Emitter: ≤ 20 mA, receiver: ≤ 20 mA ≤ 30 mA NPN open collector output / PNP open collector output mod ≤ 30 VDC = ≤ 100 mA NPN: ≤ 1 VDC =, PNP: ≤ 2 VDC = Reverse power protection circuit, output short overcurrent p ≥ 20 M Ω (500 VDC = megger) ±240 VDC = the square wave noise (pulse width: 1 μ s) by th 1,000 VAC ~ 50/60 Hz for 1 min 1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 m for 2 hours 500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx -25 to 60 °C, storage: -40 to 70 °C (no freezing or condensa 55 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensa 1P65 (IEC standard) Cable type / Connector type model Ø 4 mm, 3-wire (Emitter: 2-wire), 2 m AWG26 (0.52 mm, 20-core), insulator outer diameter: Ø 1 mm M8 4-pin plug type				





General

Photoelectric Sensors

BM Series



Features

- Easy to mount at a narrow space with small size and light weight
- Built-in external sensitivity adjuster (Diffuse reflective type only)
- $\boldsymbol{\cdot}$ Easy to mount by screw type in mounting hole
- Built-in reverse power protection circuit and output short overcurrent protection circuit

Specifications

Model	BM3M-TDT	BM1M-MDT	BM200-DDT			
Sensing type	Through-beam	Retroreflective	Diffuse reflective			
Sensing distance	3 m	1 m ⁰¹⁾	200 mm ⁰²⁾			
Sensing target	Opaque materials	Opaque materials	Opaque materials, translucent materials			
Min. sensing target	≥ Ø 8 mm	≥ Ø 60 mm	-			
Hysteresis	-	-	≤ 10 % of sensing distance			
Response time	≤ 3 ms					
Light source	Infrared					
Peak emission wavelength	940 nm					
Sensitivity adjustment	-	-	YES (Adjuster)			
Operation mode	Dark ON mode	Dark ON mode	Light ON mode (option: Dark ON mode)			
Indicator	Operation indicator (red)					
Approval	C€ EHI	C€ EHI	C € EHI			
Unit weight (packaged) ≈ 170 g (≈ 240 g) ≈ 105 g (≈ 188 g) ≈ 88 g (≈ 156 g		≈ 88 g (≈ 156 g)				

01) Reflector (MS-2)
02) Non-glossy white paper 200 × 200 mm

12) Non-glossy writte paper 200 × 200 mm						
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)					
Current consumption	It depends on the sensing type					
Through-beam	Emitter: ≤ 45 mA, receiver: ≤ 45 mA					
Reflective	≤ 40 mA					
Control output	NPN open collector output					
Load voltage	≤ 30 VDC==					
Load current	≤ 100 mA					
Residual voltage	≤ 1.5 VDC==					
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit					
Insulation resistance	≥ 20 MΩ (500 VDC== megger)					
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator					
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min					
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours					
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times					
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx					
Ambient temperature	-10 to 60 °C, storage: -25 to 70 °C (no freezing or condensation)					
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)					
Protection rating	-					
Connection	Cable type					
Cable spec.	Ø 4 mm, 3-wire, 2 m (Emitter: Ø 3 mm, 2-wire, 2 m)					
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm					
Material	Case: ABS, sensing part: PC (through-beam type) or Acrylic (retroreflective, diffuse reflective type), bracket: SPCC, bolt: SCM, nut: SCM					



Side Sensing

Photoelectric Sensors

BMS Series



Features

- ${\boldsymbol \cdot}$ Built-in reverse polarity protection circuit and output short overcurrent protection circuit
- Response time: Max. 1 ms
- Light ON / Dark ON mode selectable by control wire
- · Sensitivity adjuster (except for through-beam type)

Specifications

Model	BMS5M-TDT-□	BMS2M-MDT-□	BMS300-DDT-□
Sensing type	Through-beam	Retroreflective	Diffuse reflective
Sensing distance	5 m	0.1 to 2 m ⁰¹⁾	300 mm ⁰²⁾
Sensing target	Opaque materials	Opaque materials	Opaque materials, translucent materials
Min. sensing target	≥ Ø 10 mm	≥ Ø 60 mm	-
Hysteresis	-	-	≤ 20 % of sensing distance
Response time	≤1 ms		
Light source	Infrared		
Peak emission wavelength	940 nm		
Sensitivity adjustment	-	YES (Adjuster)	YES (Adjuster)
Operation mode	Light ON mode - Dark ON mode selectable (control wire)		
Indicator	Operation indicator (red), power indicator(red) 03)		
Approval	C€ EHI	C € ERI	C€ EHI
Unit weight	≈ 180 g	≈ 110 g	≈ 100 g

- 01) Reflector (MS-2) 02) Non-glossy white paper 100 × 100 mm 03) Only for the emitter

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Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)
Current consumption	It depends on the sensing type
Through-beam	Emitter: ≤ 50 mA, receiver: ≤ 50 mA
Reflective	≤ 45 mA
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 30 VDC==
Load current	≤ 200 mA
Residual voltage	NPN: ≤ 1 VDC, PNP: ≤ 2.5 VDC
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-10 to 60 °C, storage: -25 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	-
Connection	Cable type
Cable spec.	Ø 5 mm, 4-wire (Emitter: 2-wire), 2 m
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm
Material	Case: ABS, sensing part: PC (through-beam type) or Acrylic (retroreflective, diffuse reflective type), bracket: SPCC, bolt: SCM, nut: SCM



Photoelectric Sensors

with Synchronous Detection

BY Series



Features

- Small size: W 12 × H 30 × L 16 mm
- Minimize malfunction by extraneous light by synchronizing emitter and receiver
- Reverse power protection circuit, output short overcurrent protection circuit
- Fast response speed: Max.1 ms

Specifications

Model	BY□500-TDT
Sensing type	Through-beam
Sensing distance	500 mm
Sensing target	Opaque materials
Min. sensing target	≥ Ø 5 mm
Response time	≤1 ms
Light source	Infrared
Peak emission wavelength	940 nm
Operation mode	Dark ON mode
Indicator	Operation indicator (red)
Approval	C € ERIC
Unit weight	≈ 150 g
Power supply	12-24 VDC== ±10% (ripple P-P: ≤ 10%)
Current consumption	Emitter: ≤ 30 mA, receiver: ≤ 30 mA
Control output	NPN open collector output
Load voltage	≤ 30 VDC==
Load current	≤ 100 mA
Residual voltage	≤1 VDC==
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	± 240 VDC== the square wave noise (pulse width: 1 μ s) by the noise simulator
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-10 to 60 °C, storage: -25 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP50 (IEC standard)
Connection	Cable type
Cable spec.	Ø 4 mm, 4-wire (Emitter: 3-wire), 2 m
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm
Material	Case: ABS, sensing part: Acrylic, bracket: SPCC, bolt: SCM, nut: SCM



Photoelectric Sensors

with Built-In Timer

BYD Series



Features

- ${\boldsymbol \cdot}$ Easy installation by compact size
- Superior detection not affected by color of target (convergent reflective type)
- Operation indicator is located on the top (BYD30-DDT-U, BYD50-DDT-U)
- Easy to adjust the response time via timer function (OFF Delay Time: 0.1 to 2 sec)
- Reverse power protection circuit, output short overcurrent protection circuit

Specifications

Model	BYD3M-TDT-□	BYD100-DDT	BYD□-DDT-□	
Sensing type	Through-beam	Diffuse reflective	Convergent reflective	
Sensing distance	3 m	100 mm 01)	10 to 30 mm ±10% ⁰¹⁾ 10 to 50 mm ±10% ⁰¹⁾	
Sensing target	Opaque materials	Opaque materials, translucent materials	Opaque materials, translucent materials	
Min. sensing target	≥ Ø 6 mm	-	-	
Hysteresis	-	≤ 25 % of sensing distance	≤ 10 % of sensing distance	
Response time	≤ 1 ms	Operation: ≤ 3 ms Return: ≤ 100 ms	Operation: ≤ 3 ms Return: ≤ 100 ms ⁰²⁾	
Light source	Infrared	Infrared	Infrared	
Sensitivity adjustment	-	YES (Adjuster)	-	
Timer function	-	-	OFF delay mode: 0.1 to 2 sec (Adjuster)	
Operation mode	Dark ON mode	Light ON mode	Light ON mode	
Indicator	Front	Front	Front / Upper operation indicator model	
	Operation indicator (red)			
Approval	C € EHI	C € EHI	C € ERI	
Unit weight (packaged)	≈ 80 g (≈ 105 g)	≈ 38 g (≈ 75 g)	≈ 38 g (≈ 75 g)	

01) Non-glossy white paper 50 × 50 mm
02) When the timer adjuster is set to min (0.1 sec).

D2) when the timer adjuster is set to min (0.1 sec).		
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)	
Current consumption	It depends on the sensing type	
Through-beam	Emitter: ≤ 30 mA, receiver: ≤ 30 mA	
Reflective	≤ 35 mA	
Control output	Through-beam type: NPN open collector output / PNP open collector output model Diffuse reflective, convergent reflective type: NPN open collector output	
Load voltage	≤ 30VDC==	
Load current	Through-beam type : ≤ 100 mA Diffuse reflective, convergent reflective type : ≤ 50 mA	
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==	
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit	
Insulation resistance	≥ 20 MΩ (500 VDC== megger)	
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator	
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min	
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours	
Shock	500 m/s 2 (\approx 50 G) in each X, Y, Z direction for 3 times	
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx	
Ambient temperature	-20 to 65 °C, storage: -25 to 70 °C (no freezing or condensation)	
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)	
Protection rating	Through-beam, convergent reflective type (front operation indicator model) : IP64 (IEC standard), Others: IP50 (IEC standard)	
Connection	Cable type	
Cable spec.	Ø 3.5 mm, 3-wire (Emitter: 2-wire), 2 m	
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1 mm	
Material	Case: ABS, sensing part: Acrylic, bracket: SPCC, bolt: SCM, nut: SCM, sleeve: Brass, Ni-plate	



Front / Side Mount

Photoelectric Sensors

BH Series



Features

- Easy front (M18 nut) and side (M3 bolt/nut) installation
- \cdot NPN open collector / PNP open collector simultaneous output
- Sensing distance: Through-beam type 20 m / Polarized retroreflective type 4 m / Diffuse reflective type 1 m, 300 mm
- Small size: W 14 × H 34.5 × L 28 mm
- · M.S.R. (Mirror Surface Rejection) function prevents malfunction from reflective objects such as metals or mirrors (polarized retroreflective type)
- Built-in sensitivity adjuster
- · Light ON / Dark ON selectable by switch
- · Operation indicator (red), stability indicator (green)
- · Reverse power protection circuit, output short overcurrent protection circuit
- Mutual interference prevention function (except through-beam type)
- IP67 protection rating (IEC standard)



View product detail

Specifications

Model	BH20M-TDT	BH4M-PDT	BH□-DDT	
Sensing type	Through-beam	Polarized retroreflective	Diffuse reflective	
Sensing distance	20 m	4 m ⁰¹⁾	300 mm ⁰²⁾	1 m ⁰³⁾
Sensing target	Opaque materials	Opaque materials	-	
Min. sensing target	≥ Ø 20 mm	≥ Ø 75 mm	-	
Hysteresis	-	-	≤ 20 % of sensing	g distance
Response time	≤1ms			
Light source	Red	Red	Red	Infrared
Peak emission wavelength	660 nm	660 nm	660 nm	850 nm
Sensitivity adjustment	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)	
Mutual interference prevention	-	YES	YES	
Operation mode	Light ON mode - Dark ON mode selectable (Adjuster)			
Indicator	Operation indicator (red), stability indicator (green), power Indicator (green) 04)			
Approval	C € : Wus ustra [A[CE (VI) US LISTED [H[C€ (VL) US LISTED [∏[
Unit weight (packaged)	≈ 120 g (≈ 190 g)	≈ 60 g (≈ 140 g)	≈ 60 g (≈ 130 g)	

- 01) Reflector (MS-2A)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

U4) Only for the emitter	
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)
Current consumption	It depends on the sensing type
Through-beam	Emitter: ≤ 20 mA, receiver : ≤ 20 mA
Polarized retroreflective	≤ 30 mA
Diffuse reflective (300 mm)	≤ 30 mA
Diffuse reflective (1 m)	≤ 35 mA
Control output	NPN open collector - PNP open collector simultaneous output
Load voltage	≤ 26.4 VDC==
Load current	≤ 100 mA
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Dielectric strength	1,000 VAC $\sim 50/60$ Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-25 to 55 °C, storage: -40 to 70 °C 01 (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP67 (IEC standard)
Connection	Cable type
Cable spec.	Ø 4 mm, 4-wire (Emitter: 2-wire), 2.1 m
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1.03 mm
Material	Case: PC, CAP: PC, sensing part: PMMA

01) UL approved ambient temperature 40°C

Diffuse Reflective Long-Distance

Photoelectric Sensors

BA Series



Features

- Realization of long sensing distance (2 m) by special optical design
- Built-in stability indicator
- · Sensitivity adjustment function
- 2 color display
- IP64 protection rating (IEC standard)

Specifications

Model	BA2M-DDT□-□
Sensing type	Diffuse reflective
Sensing distance	2 m ⁰¹⁾
Sensing target	Opaque materials, translucent materials
Hysteresis	≤ 20 % of sensing distance
Response time	≤1 ms
Light source	Infrared
Peak emission wavelength	850 nm
Sensitivity adjustment	YES (Adjuster)
Operation mode	Light ON mode / Dark ON mode model
Indicator	Operation indicator (red), stability indicator (Light ON: orange, Dark ON: green)
Approval	C€ EHI
Unit weight	≈ 50 g
01) Non-glossy white paper 20	0 × 200 mm

01) Non-glossy writte paper 20	0 ^ 200 11111
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10%)
Current consumption	≤ 15 mA (output ON: ≤ 30 mA)
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 26.4 VDC==
Load current	≤ 100 mA
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	100 m/s² (≈ 10 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-25 to 55 °C, storage: -25 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP64 (IEC standard)
Connection	Cable type
Cable spec.	Ø 3 mm, 3-wire, 2 m
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1 mm
Material	Case: ABS, CAP: PC, sensing part: PC, adjuster: IXEF



L 3.7 mm Flat

Photoelectric Sensors

BTF Series



Features

- \cdot Ultra-thin size of only 3.7 mm
- W 13 \times H 19 \times L 3.7 mm (Through-beam type)
- W 13 \times H 24 \times L 3.7 mm (Diffuse reflective type, BGS reflective type)
- · Detection methods and minimum target size
- Through-beam type (BTF1M): Ø 2 mm
- Diffuse reflective type (BTF30): Ø 0.2 mm (sensing distance: 10 mm)
- BGS reflective type (BTF15): Ø 0.2 mm (sensing distance: 10 mm)
- BGS (background suppression) minimizes detection errors from background objects and the color or material of target objects.
- Maximum sensing distance:1 m (Through-beam type)
- Operation indicator (red) and stability indicator (green) show operation status
- $\cdot \, \text{Stainless steel (SUS304) mounting brackets} \\$
- IP67 protection rating (IEC standard)

Specifications

	BTE414 TBT	DTEAS DET[] []	DT545 DDT	
Model	BTF1M-TDT□-□	BTF30-DDT□-□	BTF15-BDT□-□	
Sensing type	Through-beam	Diffuse reflective	BGS reflective	
Sensing distance	1 m	5 to 30 mm ⁰¹⁾	1 to 15 mm ⁰¹⁾	
Sensing target	Opaque materials	Opaque materials, translucent materials	Opaque materials, translucent materials	
Min. sensing target	≥ Ø 2 mm	≥ Ø 0.2 mm ⁰²⁾	≥ Ø 0.2 mm non-illuminated objects ⁰²⁾	
Hysteresis	-	≤ 20% of sensing distance	≤ 5% of sensing distance	
Black/white difference	-	-	≤ 15% of sensing distance	
Response time	≤1ms			
Light source	Red			
Peak emission wavelength	650 nm			
Operation mode	Light ON mode / Dark ON mode model			
Indicator	Operation indicator (red), stability indicator (green)			
Approval	C € EHI	C€ EHI	C€ EHI	
Unit weight (packaged)	≈ 40 g (≈ 70 g)	≈ 25 g (≈ 40 g)	≈ 25 g (≈ 40 g)	

01) Non-glossy white paper 50 × 50 mm 02) Sensing distance 10 mm



L 7.5 mm Flat

Photoelectric Sensors

BPS Series



Features

- $\boldsymbol{\cdot}$ Easy to mount by flat type
- Realization of 3m sensing distance as small size
- IP67 protection rating (IEC standard)

Specifications

Model	BPS3M-TDT□-□
Sensing type	Through-beam
Sensing distance	3 m
Sensing target	Opaque materials
Min. sensing target	≥ Ø 5 mm
Response time	≤1 ms
Light source	Infrared
Peak emission wavelength	850 nm
Operation mode	Light ON mode / Dark ON mode model
Indicator	Power Indicator of emitter (red), operation indicator of receiver (red)
Approval	C€ ERI
Unit weight	≈ 66 g
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)
Current consumption	Emitter: ≤ 20 mA, receiver: ≤ 20 mA
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 30 VDC==
Load current	≤ 100 mA
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC megger)
Noise immunity	± 240 VDC— the square wave noise (pulse width: 1 $\mu s)$ by the noise simulator
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-25 to 65 °C, storage: -25 to 70 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 90 %RH (no freezing or condensation)
Protection rating	IP67 (IEC standard)
Connection	Cable type
Cable spec.	Ø 3 mm, 3-wire (Emitter: 2-wire), 2 m
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1 mm
Material	Case: PC, bolt: SCM, nut: SCM



Cylindrical

Photoelectric Sensors

(Front Sensing Type)

BRQ Series



Features

- Excellent noise immunity and minimal influence from ambient light
- Reverse power protection circuit, reverse output protection circuit, output short overcurrent protection circuit
- · Mutual interference prevention function (except through-beam type)
- · Sensitivity adjuster
- · Light ON / Dark ON mode selectable by control wire
- · Various materials: Plastic, Metal (Ni-plated Brass), SUS316L
- · Long sensing distance: 30 m (through-beam type)
- Body size
- BRQT, BRQM: Standard
- BRQP: Standard, Short body
- Protection rating
- BRQT: IP67 (IEC standard), IP69K (DIN standard)
- BRQM, BRQP: IP67 (IEC standard)

View product detail

Specifications

Model	BRQ∐L]-T D T□-[BRQ□3M-PDT□-□-□	BRQ∟⊔-C	DT 🗆 - 🗆 -	J
Sensing type	Through	-beam		Polarized retroreflective	Diffuse refl	ective	
Sensing distance	5 m	20 m	30 m	3 m ⁰¹⁾	100 mm ⁰²⁾	400 mm ⁰²⁾	1 m ⁰³⁾
Sensing target	Opaque	materials		Opaque materials	Opaque, tra	anslucent m	aterials
Min. sensing target	≥ Ø 7 mr	n		≥ Ø 75 mm	-		
Hysteresis	-			-	≤ 20 % of s	ensing dista	ance
Response time	≤ 1 ms						
Light source	Red			Red	Infrared	Red	Red
Peak emission wavelength	660 nm			660 nm	850 nm	660 nm	660 nm
Sensitivity adjustment	YES (Ad	juster)		YES (Adjuster)	YES (Adjuster)		
Mutual interference prevention	-			YES	YES		
Operation mode	Light ON	l mode - E	Oark ON m	ode selectable (Control wire)			
Indicator	Operation	n indicato	r (yellow)	, stability indicator (green), po	ower indicato	r (red) 04)	
Approval	(€ ° Я Л	us EAC		C€ c PN us ER[(€ c % us [AC .	

- 01) Reflector (MS-2A)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

Material

Unit weight (packaged)	Material	Through-beam	Polarized retroreflective, Diffuse reflective
Cable type	SUS316L	≈ 140 g (≈ 220 g)	≈ 70 g (≈ 150 g)
	Brass, Ni-plate	≈ 140 g (≈ 220 g)	≈ 70 g (≈ 150 g)
	Plastic	≈ 110 g (≈ 160 g)	≈ 60 g (≈ 120 g)
	Plastic (short)	≈ 100 g (≈ 150 g)	≈ 50 g (≈ 120 g)
Connector type	SUS316L	≈ 50 g (≈ 160 g)	≈ 30 g (≈ 140 g)
	Brass, Ni-plate	≈ 50 g (≈ 160 g)	≈ 30 g (≈ 140 g)
	Plastic	≈ 25 g (≈ 110 g)	≈ 15 g (≈ 110 g)
	Plastic (short)	≈ 20 g (≈ 100 g)	≈ 10 g (≈ 100 g)
Device events	10 20 \/DC +10 8/ (ripple B	D: < 10.9()	

	Plastic	≈ 25 g (≈ 110 g)	≈ 15 g (≈ 110 g)				
	Plastic (short)	≈ 20 g (≈ 100 g)	≈ 10 g (≈ 100 g)				
Power supply	10-30 VDC== ±10 % (ripple P-	10-30 VDC== ±10 % (ripple P-P: ≤ 10 %)					
Current consumption	It depends on the sensing typ	pe					
Through-beam	Emitter: ≤ 20 mA, receiver: ≤	20 mA					
Reflective	≤ 30 mA						
Control output	NPN open collector output / F	PNP open collector output mod	el				
Load voltage	≤ 30 VDC==						
Load current	≤ 100 mA						
Residual voltage	NPN: ≤ 2 VDC==, PNP: ≤ 2 VE	OC==					
Protection circuit	Reverse power/output protec	tion circuit, output short overcu	ırrent protection circuit				
Insulation resistance	≥ 20 MΩ (500 VDC== megger	r)					
Noise immunity	±240 VDC== the square wave	e noise (pulse width: 1 µs) by th	e noise simulator				
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min						
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours						
Shock	500 m/s² (≈ 50 G) in each X,	Y, Z direction for 3 times					
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx						
Ambient temperature	-25 to 60 °C, storage: -30 to	70 °C (no freezing or condensa	ition)				
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)						
Protection rating	IP67 (IEC standard), SUS316L	_ material model: IP67 (IEC star	ndard), IP69K (DIN standard)				
Connection	Cable type / Connector type model						
Cable spec.	Ø 4 mm, 4-wire, (Emitter: 2-w	vire), 2 m					
Wire spec.	AWG26 (0.52 mm, 20-core), i	nsulator outer diameter: Ø 1 mr	n				
Connector	M12 4-pin plug type						

Case: It depends on the model. (refer to 'Ordering Information'), lens and lens cover: PMMA

Cylindrical

Photoelectric Sensors

(Side Sensing Type)

BRQ Series



Features

- Excellent noise immunity and minimal influence from ambient light
- Reverse power protection circuit, reverse output protection circuit, output short overcurrent protection circuit
- · Mutual interference prevention function (except through-beam type)
- · Sensitivity adjuster
- · Light ON / Dark ON mode selectable by control wire
- Protection rating: IP67 (IEC standard)

Specifications

Model	BRQPS□-TD	ΓA-□ -□	BRQPS3M-PDTA-□-□	BRQPS□-DDTA-□-□]-□
Sensing type	Through-bear	n	Polarized retroreflective	Diffuse r	Diffuse reflective	
Sensing distance	10 m	20 m	3 m ⁰¹⁾	100 mm	400 mm	700 mm
Sensing target	Opaque materials		Opaque materials	Opaque, translucent materials		
Min. sensing target	≥ Ø 7 mm		≥ Ø 75 mm	-	-	
Hysteresis	-		-	≤ 20 % of sensing distance		distance
Response time	≤ 1 ms					
Light source	Red		Red	Red		
Peak emission wavelength	660 nm		660 nm	660 nm		
Sensitivity adjustment	YES (Adjuster))	YES (Adjuster)	YES (Adjuster)		
Mutual interference prevention	-		YES	YES		
Operation mode	Light ON mod	e - Dark ON mo	ode selectable (Control wire)			
Indicator	Operation indi	cator (yellow),	stability indicator (green), power	er indicato	r (red) ⁰⁴⁾	
Approval	C€ c 9U us [H[C€ c 91 ′us [∏[C€ c PU us ERI		

- 01) Reflector (MS-2S)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 200 × 200 mm
 04) Only for the emitter

04) Only for the emitter					
Unit weight (packaged)	Through-beam	Polarized retroreflective, Diffuse reflective			
Cable type	≈ 120 g (≈ 170 g)	≈ 70 g (≈ 130 g)			
Connector type	≈ 35 g (≈ 120 g)	≈ 25 g (≈ 120 g)			
Power supply	10-30 VDC== ±10 % (ripple P-P: ≤ 10 %)				
Current consumption	It depends on the sensing type				
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 20 mA				
Reflective	≤ 30 mA				
Control output	NPN open collector output / PNP open collector	tor output model			
Load voltage	≤ 30 VDC==				
Load current	≤ 100 mA				
Residual voltage	NPN: ≤ 2 VDC==, PNP: ≤ 2 VDC==				
Protection circuit	Reverse power/output protection circuit, output short overcurrent protection circuit				
Insulation resistance	≥ 20 MΩ (500 VDC== megger)				
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 μs) by the noise simulator				
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min				
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours				
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for	or 3 times			
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx				
Ambient temperature	-25 to 60 °C, storage: -30 to 70 °C (no freezi	ing or condensation)			
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no fre	eezing or condensation)			
Protection rating	IP67 (IEC standard)				
Connection	Cable type / Connector type model				
Cable spec.	Ø 4 mm, 4-wire, (Emitter: 2-wire), 2 m				
Wire spec.	AWG26 (0.52 mm, 20-core), insulator outer diameter: Ø 1 mm				
Connector	M12 4-pin plug type				
Material	Case: PC, lens and lens cover: PMMA				



Cylindrical

Photoelectric Sensors

BR Series



Features

- Superior noise resistance with digital signal processing
- \cdot High-speed response time under 1 ms
- Built-in reverse power protection circuit and output short overcurrent protection circuit
- Suitable for sensing in narrow space (narrow beam type)
- External sensitivity adjustment
- Light ON / Dark ON mode selectable by control wire
- IP66 protection rating (IEC standard)

Specifications

Model	BR□200-DDTN-□-□
Sensing type	Narrow beam reflective
Sensing distance	200 mm ⁰¹⁾
Sensing target	Opaque materials, translucent materials
Hysteresis	≤ 20 % of sensing distance
Response time	≤1 ms
Light source	Infrared
Peak emission wavelength	850 nm
Sensitivity adjustment	YES (Adjuster)
Operation mode	Light ON mode - Dark ON mode selectable (Control wire)
Indicator	Operation indicator (red)
Approval	C€EHL
01) Non-glossy white paper 10	0 × 100 mm

Unit weight (packaged)	Metal material model	Plastic material model		
Cable type	≈ 120 q (≈ 160 q)	≈ 100 q (≈ 140 q)		
Connector type	≈ 50 q (≈ 90 q)	≈ 30 q (≈ 70 q)		
	0 (0,	3 (3)		
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)			
Current consumption	≤ 45 mA			
Control output	NPN open collector output / PNP open collector	ctor output model		
Load voltage	≤ 30 VDC==			
Load current	≤ 200 mA			
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==			
Protection circuit	Reverse power protection circuit, output shor	rt overcurrent protection circuit		
Insulation resistance	≥ 20 MΩ (500 VDC== megger)			
Noise immunity	±240 VDC= the square wave noise (pulse width: 1 μs) by the noise simulator			
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min			
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours			
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times			
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx			
Ambient temperature	-10 to 60 °C, storage: -25 to 75 °C (no freezing	ng or condensation)		
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no fre	eezing or condensation)		
Protection rating	IP66 (IEC standard)			
Connection	Cable type / Connector type model			
Cable spec.	Ø 5 mm, 4-wire, 2 m			
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm			
Connector	M12 4-pin plug type			
Material	Case: Brass, Ni-plate (metal material model) or PA Black (plastic material model), sensing part: PC lens			



4-Channel U-Shaped

Photoelectric Sensors

BUM Series



Features

- Highly reliable 4 channel detection
- \cdot High-speed response time under 1 ms
- Built-in reverse power protection circuit and output short overcurrent protection circuit
- IP65 protection rating (IEC standard)

Specifications

Model	BUM4-40D-W-4M	BUM4-40D-W-□/A	BUM4-40D-W-□/B				
Sensing type	Through-beam						
Sensing distance	40 mm						
Sensing target	Opaque materials	Opaque materials					
Min. sensing target	≥ Ø 4 mm						
Response time	≤ 1 ms						
Light source	Infrared						
Peak emission wavelength	940 nm						
Operation mode	Dark ON mode						
Indicator	Output Indicator (red), power	indicator (green)					
Approval	C€ [HI]						
Unit weight (packaged)	≈ 500 g (≈ 510 g)	≈ 500 g (≈ 1.5 kg)	≈ 500 g (≈ 1.5 kg)				
Power supply	18-35 VDC= ±10 % (ripple P-	P: ≤ 10%)					
Current consumption	≤ 50 mA						
Control output	NPN open collector output (individual 4 output)						
Load voltage	≤ 35 VDC=						
Load current	≤ 100 mA						
Residual voltage	≤ 4 VDC==	≤ 4 VDC==					
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit						
Insulation resistance	≥ 20 MΩ (500 VDC= megger	·)					
Noise immunity	±240 VDC== the square wave	e noise (pulse width: 1 µs) by th	ne noise simulator				
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 m $^{\circ}$	in					
Vibration	1.5 mm double amplitude at fro for 2 hours	equency of 10 to 55 Hz (for 1 n	nin) in each X, Y, Z direction				
Shock	500 m/s ² (\approx 50 G) in each X, Y	Y, Z direction for 3 times					
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx						
Ambient temperature	-25 to 65 °C, storage: -25 to 70 °C (no freezing or condensation)						
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)						
Protection rating	IP65 (IEC standard)						
Connection	Cable type						
Cable spec.	Ø 6 mm, 8-wire, 2 m / 3 m / 4 $$	m model					
Wire spec.	AWG22 (1.2 mm, 60-core)						
Material	Case, cover: ABS						



1-Channel U-Shaped

Photoelectric Sensors

BUP Series



Features

- Various sensing distance's lineup:30 mm, 50 mm models
- \cdot High speed response type: Max. 1 ms
- · Offers the sensitivity adjustable model
- Light ON / Dark ON operation mode selectable by control wire

Specifications

Model	BUP-□-□		BUP-□-E		BUP-□S-□			
Sensing type	Through-bea	m						
Sensing distance	30 mm	50 mm	30 mm	50 mm	30 mm	50 mm		
Sensing target	Opaque materials							
Min. sensing target	≥ Ø 4 mm				≥ Ø 1.5 mm			
Response time	≤ 1 ms							
Light source	Infrared							
Peak emission wavelength	940 nm							
Sensitivity adjustment	Fixed				YES (Adjuster	·)		
Operation mode	Light ON mod	de - Dark ON mo	ode selectable (Control wire)				
Indicator	Operation inc	licator (red), pov	wer indicator (g	reen)				
Approval	C € EHI		C€		C€ EHI			
Unit weight (packaged)	≈ 85 g (≈ 120 g)	≈ 115 g (≈ 160 g)	≈ 60 g (≈ 95 g)	≈ 90 g (≈ 125 g)	≈ 85 g (≈ 120 g)	≈ 115 g (≈ 160 g)		
Power supply	12-24 VDC=	±10 % (ripple P	-P: ≤ 10%)					
Current consumption	≤ 30 mA							
Control output	NPN open collector output / PNP open collector output model							
Load voltage	≤ 30 VDC==	≤ 30 VDC==						
Load current	≤ 200 mA							
Residual voltage	NPN: ≤ 1 VDC	NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==						
Protection circuit	Reverse pow	Reverse power protection circuit, output short overcurrent protection circuit						
Insulation resistance	≥ 20 MΩ (500 VDC== megger)							
Noise immunity	±240 VDC==	the square wav	e noise (pulse v	vidth: 1 µs) by tl	ne noise simulat	tor		
Dielectric strength	1,000 VAC~	50/60 Hz for 1 n	nin					
Vibration	1.5 mm doubl for 2 hours	e amplitude at f	requency of 10	to 55 Hz (for 1 i	min) in each X, \	/, Z direction		
Shock	500 m/s² (≈ 5	50 G) in each X,	Y, Z direction for	or 3 times				
Ambient illuminance (receiver)	Sunlight: ≤ 11	,000 lx, incande	scent lamp: ≤ 3	,000 lx				
Ambient temperature	Fixed sensitivity model: -25 to 65 °C, storage: -25 to 70 °C (no freezing or condensation) Sensitivity adjustable model: -10 to 60 °C, storage: -25 to 70 °C (no freezing or condensation)							
Ambient humidity	35 to 85 %RF	H, storage: 35 to	85 %RH (no fre	eezing or conde	ensation)			
Protection rating	Fixed sensitivity model: IP66 (IEC standard) Sensitivity adjustable model: IP50 (IEC standard)							
Connection	Cable type, c	able connector	type					
Cable spec.	Cable type: Ø 4 mm, 4-wire, 2 m Cable connector type: Ø 4 mm, 4-wire, 0.5 m							
Wire spec.	AWG22 (0.08	mm, 60-core),	insulator outer	diameter: Ø 1.2	5 mm			
Connector	5-pin socket	5-pin socket type						
Material	Case: ABS, C	AP: PC						



Universal AC / DC

Photoelectric Sensors

BEN Series



Features

- $\boldsymbol{\cdot}$ Small and power supply built-in type
- ${\boldsymbol \cdot}$ Easy installation with indicators on product
- · Light ON / Dark ON mode selectable by switch
- · Status and output indication
- Built-in IC photo diode for disturbing light and electrical noise

Specifications

Model	BEN10M-T	вен5м-м 🗔	ВЕN3М-Р	BEN300-D	
Sensing type	Through-beam	Retroreflective	Polarized retroreflective	Diffuse reflective	
Sensing distance	10 m	0.1 to 5 m ⁰¹⁾	0.1 to 3 m ⁰¹⁾	300 mm ⁰²⁾	
Sensing target	Opaque materials	Opaque materials	Opaque materials	Opaque, translucent materials	
Min. sensing target	≥ Ø 16 mm	≥ Ø 60 mm	≥ Ø 60 mm	-	
Hysteresis	-	-	-	≤ 20 % of sensing distance	
Response time	AC/DC power, relay contact output model: ≤ 20 ms DC power, solid state (transistor) output model: ≤ 1 ms				
Light source	Infrared	Infrared	Red	Infrared	
Peak emission wavelength	850 nm	940 nm	660 nm	940 nm	
Sensitivity adjustment	-	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)	
Operation mode	Light ON mode - Dark	ON mode selectable (A	Adjuster)		
Indicator	Operation indicator (red), stability indicator (green), power indicator (red) 031				
Approval	C € ERIC				
Unit weight (AC/DC power)	≈ 354 g	≈ 208 g	≈ 208 g	≈ 195 g	
Unit weight (DC power)	≈ 342 g	≈ 200 g	≈ 200 g	≈ 187 g	

- 01) Reflector (MS-2) 02) Non-glossy white paper 100 × 100 mm 03) Only for the emitter

oo, omy for the emitter			
Output method	AC/DC power, relay contact output	DC power, solid state (transistor) output	
Power supply	24-240 VAC~ ± 10 % 50/60 Hz 24-240 VDC== ± 10 % (ripple P-P: ≤ 10 %)	12-24 VDC== ± 10 % (ripple P-P: ≤ 10 %)	
Power / current consumption	≤ 4 VA	It depends on the sensing type	
Through-beam	-	Emitter: ≤ 50 mA, receiver: ≤ 50 mA	
Reflective	-	≤ 50 mA	
Control output	Relay contact output	NPN open collector - PNP open collector simultaneous output	
Contact capacity	250 VAC~ 3 A of resistance load, 30 VDC= 3 A of resistance load	-	
Contact composition	1c		
Relay life cycle	Mechanical: ≥ 50,000,000 Electrical: ≥ 100,000		
Load voltage	-	≤ 30 VDC	
Load current		≤ 200 mA	
Residual voltage		NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==	
Protection circuit	-	Reverse power protection circuit, output short overcurrent protection circuit	
Insulation resistance	≥ 20 MΩ (500 VDC== megger)		
Insulation type	Double or strong insulation (dielectric voltage between the measured input and the power:1kV)	-	
Noise immunity	± 1,000 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator	



Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min		
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours		
Vibration (malfunction)	1.5 mm double amplitude at frequency of 10 - to 55 Hz (for 1 min) in each X, Y, Z direction for 10 min		
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times		
Shock (malfunction)	100 m/s² (\approx 10 G) in each X, Y, Z direction for 3 times -		
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx		
Ambient temperature	-20 to 65 °C, storage: -20 to 70 °C (no freezing or condensation)		
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)		
Protection rating	IP50 (IEC standard)		
Connection	Cable type		
Cable spec.	Ø 5 mm, Emitter: 2-wire, AC/DC power: 5-wire, DC power: 4-wire, 2 m		
Wire spec.	AWG22 (0.08 mm, 60-core), insulator outer diameter: Ø 1.25 mm		
Material	Case and case cover: heat resistant ABS, sensing part: PC (polarized retroreflective: PMMA)		

Universal AC / DC

Photoelectric Sensors

BX Series



Features

- · Built-in sensitivity adjuster
- · Timer function (built-in timer model)
- ON Delay, OFF Delay, One-shot Delay
- NPN / PNP open collector simultaneous output (DC power Type)
- · Self-diagnosis function (green lights up in the stable level)
- Built-in reverse power protection circuit and output short overcurrent protection circuit
- Wide power supply range: Universal 24-240 VDC=- / 24-240 VAC \sim
- IP66 protection rating (IEC standard)

Specifications

Model	BX15M-T□-□	BX5M-M□-□	BX3M-P□-□	BX700-D□-□	
Sensing type	Through-beam	Retroreflective	Polarized retroreflective	Diffuse reflective	
Sensing distance	15 m	0.1 to 5 m ⁰¹⁾	0.1 to 3 m ⁰²⁾	700 mm ⁰³⁾	
Sensing target	Opaque materials	Opaque materials	Opaque materials	Opaque, translucent materials	
Min. sensing target	≥ Ø 15 mm	≥ Ø 60 mm	≥ Ø 60 mm	-	
Hysteresis	-	-	-	≤ 20 % of sensing distance	
Response time	AC/DC power, relay contact output model: ≤ 20 ms DC power, solid state (transistor) output model: ≤ 1 ms				
Light source	Infrared	Infrared	Red	Infrared	
Peak emission wavelength	850 nm	940 nm	660 nm	940 nm	
Sensitivity adjustment	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)	
Timer mode ⁰⁴⁾	OFF, ON Delay, OFF Delay, One Shot Delay mode selectable (Switch): 0.1 to 5 sec (Adjuster)				
Operation mode	Light ON mode - Dark ON mode selectable (Switch)				
Indicator	Operation indicator (yellow), self-diagnosis indicator (green), power indicator (yellow) 05)				
Approval	C € ERE	C € EHI	C € EHE	C € EHE	
Unit weight	Based on the standard	Based on the standard model, timer model: weight + 1 g			
AC/DC power	≈ 225 g	≈ 130 g	≈ 148 g	≈ 115 g	
DC power	≈ 211 g	≈ 123 g	≈ 141 g	≈ 116 g	
01) Peffector (MS-2)					

- 01) Reflector (MS-2)
 02) Reflector (MS-3)
 03) Non-glossy white paper 200 × 200 mm
 04) Only for the timer model
 05) Only for the emitter

Protection circuit

Output method	AC/DC power, relay contact output	DC power, Transistor solid state output
Power supply	24-240 VAC~ ± 10 % 50/60 Hz 24-240 VDC= ± 10 % (ripple P-P: ≤ 10 %)	12-24 VDC== ± 10 % (ripple P-P: ≤ 10 %)
Power / current consumption	≤ 3 VA	It depends on the sensing type
Through-beam		Emitter: ≤ 50 mA, receiver: ≤ 50 mA
Reflective		≤ 50 mA
Control output	Relay contact output	NPN open collector - PNP open collector simultaneous output
Contact capacity	250 VAC~ 3 A of resistance load, 30 VDC= 3 A of resistance load	-
Contact composition	1c	
Relay life cycle	Mechanical: ≥ 50,000,000 Electrical: ≥ 100,000	
Load voltage	-	≤ 30 VDC
Load current		≤ 200 mA
Residual voltage		NPN: ≤ 1 VDC==, PNP: ≤ 2.5 VDC==
Self-diagnosis output	-	NPN open collector output 01)

Reverse power protection circuit, output





Insulation resistance	≥ 20 MΩ (500 VDC== megger)		
Insulation type	Double or strong insulation (dielectric voltage between the measured input and the power: 1.5 kV)	-	
Noise immunity	± 1,000 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator	
Dielectric strength	1,500 VAC \sim 50/60 Hz for 1 min		
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours		
Vibration (malfunction)	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 10 min		
Shock	500 m/s 2 (\approx 50 G) in each X, Y, Z direction for 3 times		
Shock (malfunction)	100 m/s 2 (\approx 10 G) in each X, Y, Z direction for 3 times		
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx		
Ambient temperature	-20 to 55 °C, storage: -25 to 70 °C (no freezing or condensation)		
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)		
Protection rating	IP66 (IEC standard)		
Connection	Terminal type		
Material	Case, lens cover: PC, sensing part: Acrylic, bracket: SPCC, bolt: SCM, nut: SCM		

Photoelectric Sensors

for PCB Detection

BJP Series



Features

- \cdot 30 mm \times 3 mm of rectangular light beam (at 30 mm distance) provides accurate detection of PCBs regardless of holes, incomplete fabrication, protrusions, or intrusions on the boards.
- \cdot Background suppression (BGS) sensing method allows stable detection regardless of the color, texture or surface of the background object.
- Sensing distance: 10 to 100 mm (adjustable distance: 20 to 100 mm)
- Switch for selecting Light ON / Dark ON mode
- · Reverse power protection circuit, output short overcurrent protection circuit
- IP65 protection rating (IEC standard)

Specifications

Model	BJP100-BDT-□
Sensing type	BGS reflective
Sensing distance	10 to 100 mm ⁰¹⁾ (at sensing distance: 100 mm)
Sensing target	Opaque materials
Sensing distance setting	20 to 100 mm ⁰¹⁾
Hysteresis	≤ 10 % of setting distance ⁰¹⁾
Response time	≤ 1.5 ms
Light source	Red
Peak emission wavelength	660 nm
Beam spot size	W 3 × L 30 mm (at sensing distance: 30 mm)
Operation mode	Light ON mode - Dark ON mode selectable (Adjuster)
Indicator	Operation indicator (red), stability indicator (green)
Approval	C€EHE
Unit weight (packaged)	≈ 50 g (≈ 105 g)
01) Non-glossy white paper 100) × 100 mm

Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)
Current consumption	≤ 30 mA
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 26.4 VDC==
Load current	≤ 100 mA
Residual voltage	NPN: ≤ 1 VDC, PNP: ≤ 2 VDC
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	±240 VDC== the square wave noise (pulse width: 1 µs) by the noise simulator
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Sunlight: ≤ 10,000 lx, incandescent lamp: ≤ 3,000 lx
Ambient temperature	-25 to 55 °C, storage: -40 to 70°C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP65 (IEC standard)
Connection	Cable type
Cable spec.	Ø 3.5 mm, 3-wire, 2 m
Wire spec.	AWG24 (0.08 mm, 40-core), insulator outer diameter: Ø 1 mm
Material	Case: PC+ABS, CAP: PC, sensing part: PMMA



Oil-Resistant

Photoelectric Sensors

BJR Series



Features

- Long sensing distance with lens of high performance: Through-beam type 15 m, diffuse reflective type 1 m, polarized retroreflective type 3 m (MS-2S)
- M.S.R. (Mirror Surface Rejection) function (Polarized retroreflective type)
- Compact size: W 11 × H 32 × L 20 mm
- · Light ON / Dark ON operation mode switch
- Built-in sensitivity adjustment adjuster
- $\boldsymbol{\cdot}$ Reverse power protection circuit and output short overcurrent protection circuit
- ${\boldsymbol{\cdot}} \ {\bf Mutual \ interference \ prevention \ function}$ (except through-beam type)
- Excellent noise immunity and minimal influence from ambient light
- Stronger in the environment with full of cutting fluid or lubricating oil (optimized for automobile and machine tool industry)
- IP67 protection rating (IEC standard), IP67G oil resistance protection rating (JEM standard)

Specifications

Model	BJR15M-TDT-□-□	BJR3M-PDT-□-□	BJR□-DDT-□]-[]
Sensing type	Through-beam	Polarized retroreflective	Diffuse reflective	
Sensing distance	15 m	3 m ⁰¹⁾	100 mm ⁰²⁾	1 m ⁰³⁾
Sensing target	Opaque materials	Opaque materials	Opaque mater translucent ma	
Min. sensing target	≥ Ø 12 mm	≥ Ø 75 mm	-	-
Hysteresis	-	-	≤ 20 % of sen	sing distance
Response time	≤ 1 ms			
Light source	Infrared	Red	Infrared	Red
Peak emission wavelength	850 nm	660 nm	850 nm	660 nm
Sensitivity adjustment	YES (Adjuster)	YES (Adjuster)	YES (Adjuster)
Mutual interference prevention	-	YES	YES	
Operation mode	Light ON mode - Dark ON mode selectable (Adjuster)			
Indicator	Operation indicator (yellow), stability indicator (green), power indicator (red) 04)			
Approval	C€	C€	CE	

- 01) Reflector (MS-2S)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

04) Only for the emitter							
Unit weight (packaged)	Through-beam	Polarized retroreflective	Diffuse reflective				
Cable type	≈ 95 g (≈ 145 g)	≈ 50 g (≈ 115 g)	≈ 50 g (≈ 100 g)				
Cable connector type	≈ 55 g (≈ 105 g)	≈ 30 g (≈ 95 g)	≈ 30 g (≈ 80 g)				
Power supply	10-30 VDC== ±10 % (ripple P-	10-30 VDC== ±10 % (ripple P-P: ≤ 10 %)					
Current consumption	It depends on the sensing typ	It depends on the sensing type					
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 2	20 mA					
Reflective	≤ 30 mA						
Control output	NPN open collector output / F	PNP open collector output mod	el				
Load voltage	≤ 30 VDC==						
Load current	≤ 100 mA						
Residual voltage	NPN: ≤ 1 VDC==, PNP: ≤ 2 VDC==						
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit						
Insulation resistance	≥ 20 MΩ (500 VDC== megger)						
Noise immunity	±240 VDC= the square wave noise (pulse width: 1 µs) by the noise simulator						
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min						
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours						
Shock	500 m/s² (≈ 50 G) in each X, Y, Z direction for 3 times						
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx						
Ambient temperature	-25 to 60 °C, storage: -40 to 70°C (no freezing or condensation)						
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)						
Protection rating	IP67 (IEC standard), IP67G (JEM standard)						
Connection	Cable type / Cable connector type model						
Cable spec.	Ø 4 mm, 3-wire (emitter: 2-wire), cable type: 2 m, cable connector type: 300 mm						
Wire spec.	AWG26 (0.52 mm, 20-core), insulator outer diameter: Ø 1 mm						
Connector	M12 4-pin plug type						
Material	Case: ABS, CAP: PA12, sensing part: PMMA						



Oil-Proof

Photoelectric Sensors

BJR-F Series



Features

- · Long sensing distance with lens of high performance: Through-beam type 15 m, diffuse reflective type 1 m, polarized retroreflective type 3 m (MS-2S)
- M.S.R. (Mirror Surface Rejection) function (Polarized retroreflective type)
- Compact size : W 11 × H 32 × L 20 mm
- · Adjuster for Light ON / Dark ON mode
- · Sensitivity adjustment Adjuster
- Built-in reverse polarity protection circuit and output short overcurrent protection circuit
- Mutual interference prevention function (except through-beam type)
- Excellent noise immunity and minimal influence from ambient light
- Stronger in the environment with full of cutting fluid or lubricating oil (optimized for automobile and machine tool industry)
- IP67 protection rating (IEC standard), IP67F oil proof protection rating (JEM standard)



View product detail

Specifications

Model	BJR□-TDT-□]- □-F	BJR3M-PDT-□-□-F	BJR□-DDT-□]-[]-F
Sensing type	Through-beam		Polarized retroreflective	Diffuse reflective	
Sensing distance	10 m	15 m	3 m ⁰¹⁾	100 mm ⁰²⁾	1 m ⁰³⁾
Sensing target	Opaque mater	rials	Opaque materials	Opaque mater translucent ma	
Min. sensing target	≥ Ø 12 mm		≥ Ø 75 mm	-	-
Hysteresis	-		-	≤ 20 % of sensing distance	
Response time	≤1 ms				
Light source	Infrared	Red	Red	Red	Infrared
Peak emission wavelength	850 nm	660 nm	660 nm	660 nm	850 nm
Sensitivity adjustment	YES (Adjuster)		YES (Adjuster)	YES (Adjuster))
Mutual interference prevention	-		YES	YES	
Operation mode	Light ON mode - Dark ON mode selectable (Adjuster)				
Indicator	Operation indicator (yellow), stability indicator (green), power indicator (red) 04)) (4)	
Approval	C€		CE	C€	

- 01) Reflector (MS-2S)
 02) Non-glossy white paper 100 × 100 mm
 03) Non-glossy white paper 300 × 300 mm
 04) Only for the emitter

04) Only for the emitter				
Unit weight (packaged)	Through-beam	Polarized retroreflective	Diffuse reflective	
Cable type	≈ 95 g (≈ 145 g)	≈ 50 g (≈ 115 g)	≈ 50 g (≈ 100 g)	
Connector type	≈ 12 g (≈ 65 g)	≈ 6 g (≈ 75 g)	≈ 6 g (≈ 60 g)	
Cable connector type	≈ 55 g (≈ 105 g)	≈ 30 g (≈ 95 g)	≈ 30 g (≈ 80 g)	
Power supply	10-30 VDC== ±10 % (ripple P-	P: ≤ 10 %)		
Current consumption	It depends on the sensing typ	e		
Through-beam	Emitter: ≤ 20 mA, receiver: ≤ 2	20 mA		
Reflective	≤ 30 mA			
Control output	NPN open collector output / P	PNP open collector output Mod	el	
Load voltage	≤ 30 VDC==			
Load current	≤ 100 mA			
Residual voltage	NPN: ≤ 1 VDC, PNP: ≤ 2 VDC			
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit			
Insulation resistance	≥ 20 MΩ (500 VDC== megger)			
Noise immunity	± 240 VDC== the square wave noise (pulse width: 1 μ s) by the noise simulator			
Dielectric strength	1,000 VAC~ 50/60 Hz for 1 min			
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours			
Shock	500 m/s ² (\approx 50 G) in each X,	Y, Z direction for 3 times		
Ambient illuminance (receiver)	Sunlight: ≤ 11,000 lx, incandescent lamp: ≤ 3,000 lx			
Ambient temperature	-25 to 60 °C, storage: -40 to 70°C (no freezing or condensation)			
Ambient humidity	35 to 85 %RH, storage: 35 to	85 %RH (no freezing or conde	ensation)	
Protection rating	IP67 (IEC standard), IP67F (JE	M standard)		
Connection	Cable type / Connector type /	Cable connector type model		
Cable spec.	Ø 4 mm, 3-wire (Emitter: 2-wi	ire), cable type: 2 m, cable con	nector type: 300 mm	
Wire spec.	AWG26 (0.52 mm, 20-core), ii	nsulator outer diameter: Ø 1 mr	m	
Connector	Connector type: M8 4-pin plug type, cable connector type: M12 4-pin plug type			
Material	Case: ABS, CAP: PA12, sensing part: PMMA			

Color Mark

Photoelectric Sensors

BC Series



Features

- Outstanding color matching accuracy
- R.G.B light emitting diodes and 12-bit resolution
- 2 detection modes (color only / color + intensity)
- 3-step sensitivity adjustment for each mode (fine, normal, rough)
- External light interference reduction minimizes errors and allows stable detection
- $\boldsymbol{\cdot}$ Check reference color with teaching indicator
- Operation indicator (red), stability indicator (green), timer indicator (orange)
- Configure operation functions with external input from wiring
- W 1.24 × L 6.7 mm spot size for detection of tiny targets and color marks
- IP67 protection rating (IEC standard)

Specifications

Model	BC15-LDT-C-□
Sensing type	Convergent reflective
Sensing distance	15 mm ± 2 mm
Sensing target	Opaque materials, translucent materials
Hysteresis	≤ 20 % of sensing distance (may vary by sensing mode or sensitivity)
Response time	≤ 500 µs
Light source	Full Color (Red, Green, Blue)
Min. spot size	W 1.24 × L 6.7 mm
Sensing mode	C mode (color only) - C+I mode (color + intensity) selectable (SET key or SET cable)
Sensitivity adjustment	YES (SET key or SET cable)
Operation mode	Color match (Normally Open) - Color mismatch (Normally Closed) mode selectable (Adjuster)
Teaching	YES
Timer	OFF-delay mode: 40 ms
Indicator	Operation indicator (red), stability indicator (green), teaching indicator (full color), timer indicator (orange)
Approval	C € ERIC
Unit weight (packaged)	≈ 14 g (≈ 80 g)
Power supply	12-24 VDC== ±10 % (ripple P-P: ≤ 10 %)
Current consumption	≤ 30 mA
Control output	NPN open collector output / PNP open collector output model
Load voltage	≤ 30 VDC
Load current	≤100 mA
Residual voltage	NPN: ≤ 1 VDC=-, PNP: ≤ 2.5 VDC=-
Protection circuit	Reverse power protection circuit, output short overcurrent protection circuit
Insulation resistance	≥ 20 MΩ (500 VDC== megger)
Noise immunity	± 240 VDC= the square wave noise (pulse width: 1 μ s) by the noise simulator
Dielectric strength	1,000 VAC \sim 50/60 Hz for 1 min
Vibration	1.5 mm double amplitude at frequency of 10 to 55 Hz (for 1 min) in each X, Y, Z direction for 2 hours
Shock	500 m/s ² (\approx 50 G) in each X, Y, Z direction for 3 times
Ambient illuminance (receiver)	Incandescent lamp: ≤ 3,000 lx
Ambient temperature	-10 to 55 °C, storage: -25 to 75 °C (no freezing or condensation)
Ambient humidity	35 to 85 %RH, storage: 35 to 85 %RH (no freezing or condensation)
Protection rating	IP67 (IEC standard)
Connection	Connector type
Connector	M12 4-pin plug type
Material	Case: PC, sensing part: Acrylic, bracket: SUS304, bolt: Carbon Steel

